

NB3N3002

3.3V, Crystal - To- HCSL Clock Generator

Description

The NB3N3002 is a high precision, low phase noise clock generator that supports PCI-Express and Ethernet requirements. The device takes a 25 MHz fundamental mode parallel resonant crystal and generates differential HCSL output at 25 MHz, 100 MHz, 125 MHz or 200 MHz clock frequencies.

This device is housed in 5.0 mm x 4.4 mm narrow body TSSOP 16 pin package.

Features

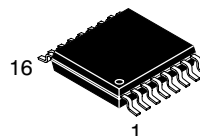
- Uses 25 MHz Fundamental Mode Parallel Resonant Crystal
- External Loop Filter is Not Required
- HCSL Differential Output
- Typical TIE RMS jitter of 2.5 ps
- Jitter or Low Phase Noise:

Offset	Noise Power
100 Hz	-103 dBc
1 kHz	-118 dBc
10 kHz	-122 dBc
100 kHz	-130 dBc
1 MHz	-138 dBc
10 MHz	-149 dBc
- Operating Range 3.3 V $\pm 5\%$
- Industrial Temperature Range -40°C to +85°C
- These are Pb-Free Devices



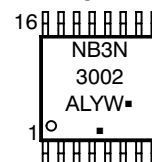
ON Semiconductor®

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**TSSOP-16
DT SUFFIX
CASE 948F**

MARKING DIAGRAM



A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

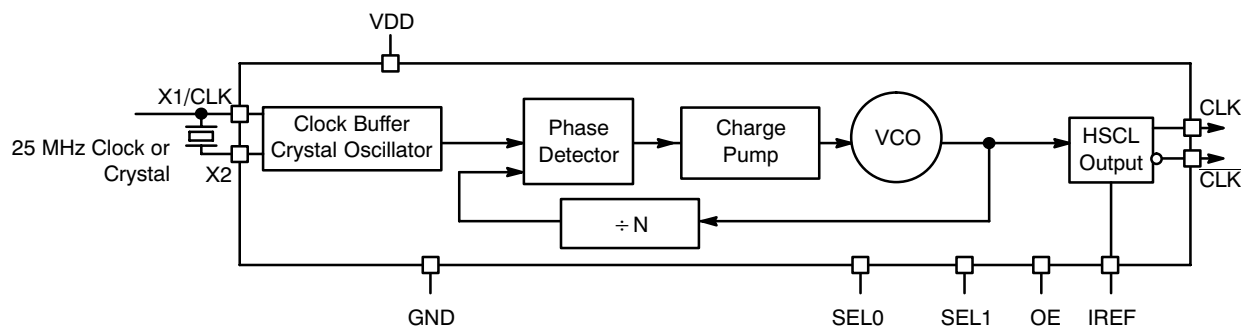


Figure 1. NB3N3002 Simplified Logic Diagram

NB3N3002

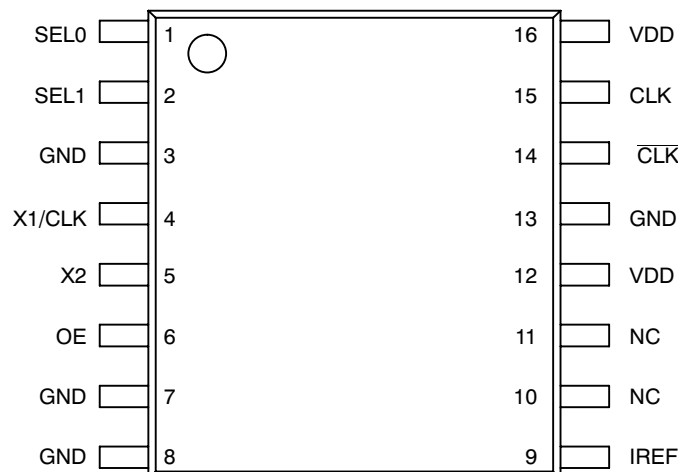


Figure 2. Pin Configuration (Top View)

Table 1. PIN DESCRIPTION

Pin	Symbol	I/O	Description
1	Sel0	Input	LVTTL/LVCMOS frequency select input 0. Internal pullup resistor to V_{DD} . See output select table 2 for details.
2	Sel1	Input	LVTTL/LVCMOS frequency select input 1. Internal pullup resistor to V_{DD} . See output select Table 2 for details.
12, 16	V_{DD}	Power Supply	Positive supply voltage pins are connected to +3.3 V supply voltage.
4	X1/CLK	Input	Crystal or Clock input. Connect to 25 MHz crystal source or single-ended clock.
5	X2	Input	Crystal input. Connect to a 25 MHz crystal or leave unconnected for clock input.
6	OE	Input	Output enable input that tri-states output. Internal pullup resistor to V_{DD} .
3, 7, 8, 13	GND	Power Supply	Ground 0 V. These pins provide GND return path for the devices.
9	I_{REF}	Output	Output current reference pin. Precision resistor (typ. 475 Ω) is connected to set the output current.
15	CLK	HCSL Output	Noninverted clock output.
14	$\overline{CLK}$	HCSL Output	Inverted clock output.
10,11	NC		Do not connect

Table 2. OUTPUT FREQUENCY SELECT TABLE

Sel1	Sel0	f_{CLKout} (MHz)
L	L	25
L	H	100
H	L	125
H	H	200

Recommended Crystal Parameters

Crystal	Fundamental AT-Cut
Frequency	25 MHz
Load Capacitance	16-20 pF
Shunt Capacitance, C0	7 pF Max
Equivalent Series Resistance	35 Ω Max
Initial Accuracy at 25 °C	± 20 ppm
Temperature Stability	± 30 ppm
Aging	± 20 ppm
C0/C1 Ration	250 Max

Table 3. ATTRIBUTES

Characteristic	Value
ESD Protection Human Body Model	> 2 kV
Moisture Sensitivity, Indefinite Time Out of Dry Pack (Note 1)	Level 3
Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in
Transistor Count	7623
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test	

1. For additional information, see Application Note AND8003/D.

Table 4. MAXIMUM RATINGS (Note 2)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V _{DD}	Positive Power Supply	GND = 0 V		4.6	V
V _I	Input Voltage (V _{IN})	GND = 0 V	GND ≤ V _I ≤ V _{DD}	-0.5 V to V _{DD} +0.5 V	V
T _A	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ _{JA}	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	TSSOP-16 TSSOP-16	138 108	°C/W °C/W
θ _{JC}	Thermal Resistance (Junction-to-Case)	(Note 3)	TSSOP-16	33 to 36	°C/W
T _{sol}	Wave Solder			265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and not valid simultaneously. If stress limits are exceeded device functional operation is not implied, damage may occur and reliability may be affected.
- JEDEC standard multilayer board - 2S2P (2 signal, 2 power).

Table 5. DC CHARACTERISTICS (V_{DD} = 3.3 V ±5%, GND = 0 V, T_A = -40°C to +85°C)

Symbol	Characteristic	Min	Typ	Max	Unit
I _{DD}	Power Supply Current (Note 4)	65		95	mA
I _{DDOE}	Power Supply Current when OE is Set Low	35		65	mA
V _{IH}	Input HIGH Voltage (X1/CLK, Sel0, Sel1, and OE)	0.7 * V _{DD}		V _{DD} + 300	mV
V _{IL}	Input LOW Voltage (X1/CLK, Sel0, Sel1, and OE)	GND - 300		0.3* V _{DD}	mV
V _{OH}	Output HIGH Voltage (See Figure 4)	660	700	850	mV
V _{OL}	Output LOW Voltage (See Figure 4)	-150	0	150	mV
V _{cross}	Crossing Voltage Magnitude (Absolute)	250		400	mV
ΔV _{cross}	Change in Magnitude of V _{cross}			150	mV

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

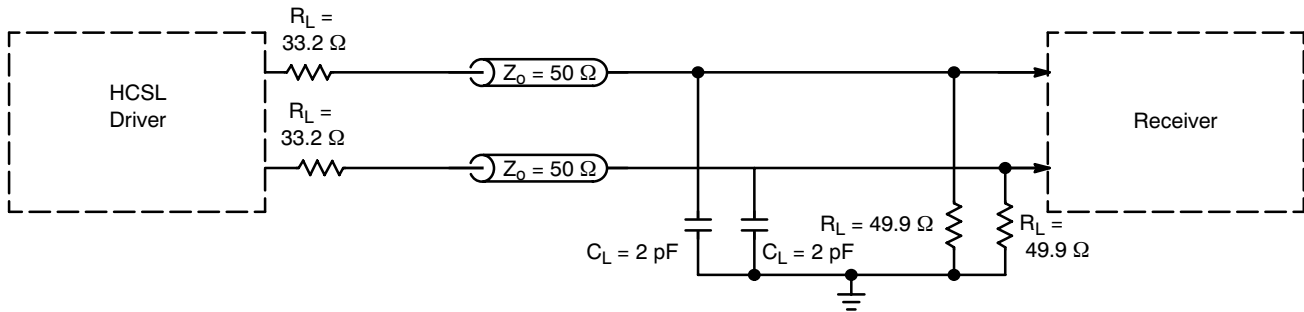
- NB3N circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500 lfpm is maintained.
- Measurement taken with outputs terminated with R_S = 33.2 Ω, R_L = 49.9 Ω, C_L = 2 pF and current biasing resistor set at 475 Ω. See Figure 4.

Table 6. Table 5. AC CHARACTERISTICS ($V_{DD} = 3.3\text{ V} \pm 5\%$, $GND = 0\text{ V}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$; Note 7)

Symbol	Characteristic	Min	Typ	Max	Unit
f_{CLKIN}	Clock/Crystal Input Frequency		25		MHz
f_{CLKOUT}	Output Clock Frequency	25		200	MHz
Ω_{NOISE}	Phase-Noise Performance $f_{CLKout} = 200\text{ MHz}$				dBc/Hz
	@ 100 Hz offset from carrier		-103		
	@ 1 kHz offset from carrier		-118		
	@ 10 kHz offset from carrier		-122		
	@ 100 kHz offset from carrier		-130		
	@ 1 MHz offset from carrier		-138		
	@ 10 MHz offset from carrier		-149		
Tjitter (TIE)	TIE RMS Jitter (Note 8) $f_{CLKout} = 200\text{ MHz}$		2.5		ps
	Cycle-to-Cycle RMS Jitter (Note 9) $f_{CLKout} = 200\text{ MHz}$		2	5	
	Cycle-to-Cycle Peak to Peak Jitter (Note 9) $f_{CLKout} = 200\text{ MHz}$		20	35	
	Period RMS Jitter (Note 9) $f_{CLKout} = 200\text{ MHz}$		1.5	3	
	Period Peak-to-Peak Jitter (Note 9) $f_{CLKout} = 200\text{ MHz}$		10	20	
OE	Output Enable/Disable Time			1.0	μs
t_{DUTY_CYCLE}	Output Clock Duty Cycle (Measured at cross point)	45	50	55	%
t_R	Output Risetime (Measured from 175 mV to 525 mV, Figure 4)	175	340	700	ps
t_F	Output Falltime (Measured from 525 mV to 175 mV, Figure 4)	175	340	700	ps
Δt_R	Output Risetime Variation (Single-Ended)			125	ps
Δt_F	Output Falltime Variation (Single-Ended)			125	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

6. NB3N circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500 lfm is maintained.
7. Measurement taken from differential output on single-ended channel terminated with $R_S = 33.2\ \Omega$, $R_L = 49.9\ \Omega$, $C_L = 2\text{ pF}$ and current biasing resistor set at $475\ \Omega$. See Figure 4.
8. Sampled with 20000 cycles to capture jitter component down to 100 kHz.
9. Sampled with 20000 cycles.

**Figure 3. Typical Termination for Output Driver and Device Evaluation**

NB3N3002

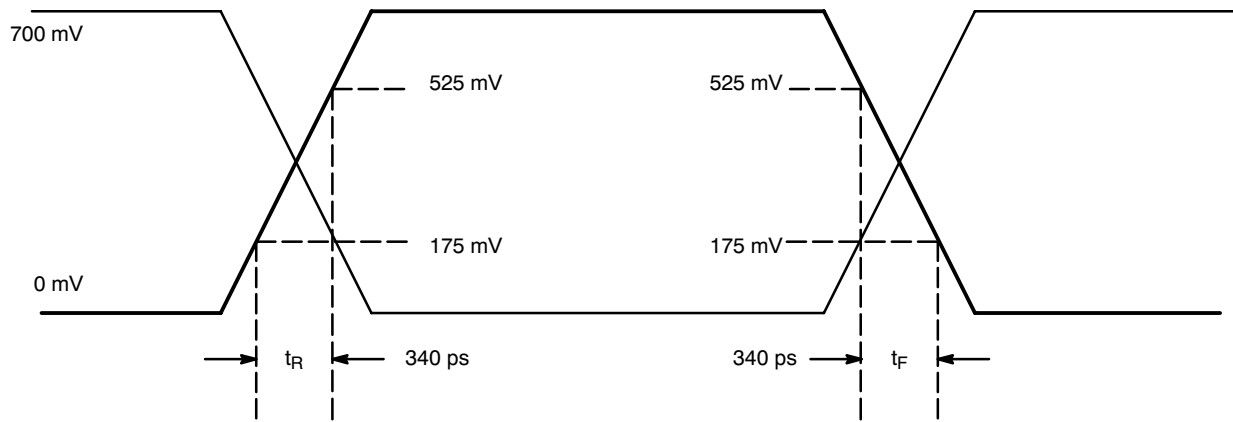


Figure 4. HCSL Output Parameter Characteristics

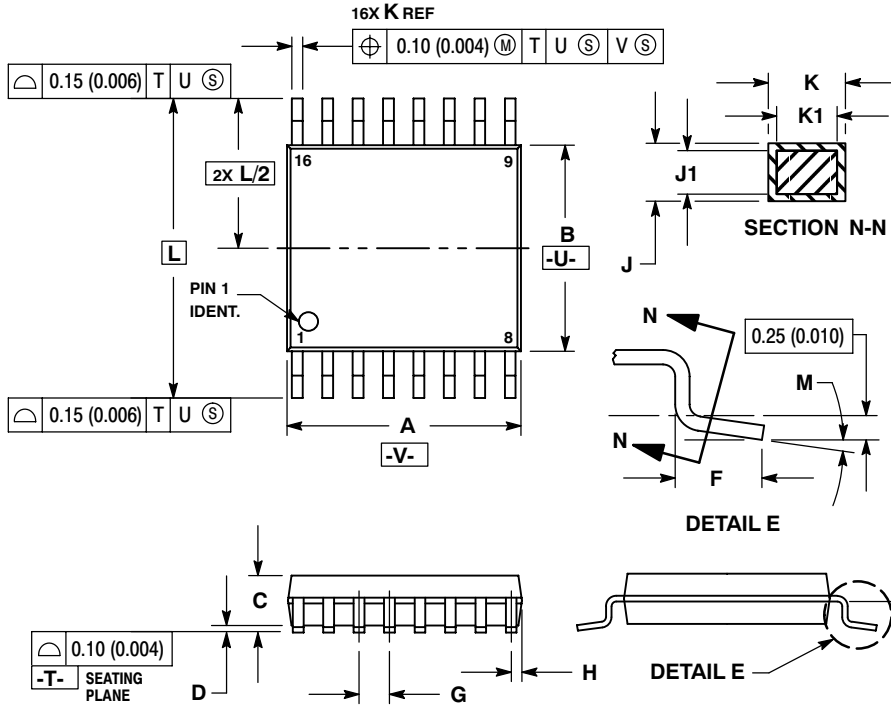
ORDERING INFORMATION

Device	Package	Shipping [†]
NB3N3002DTG	TSSOP-16 (Pb-Free)	96 Units / Rail
NB3N3002DTR2G	TSSOP-16 (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TSSOP-16
CASE 948F-01
ISSUE B

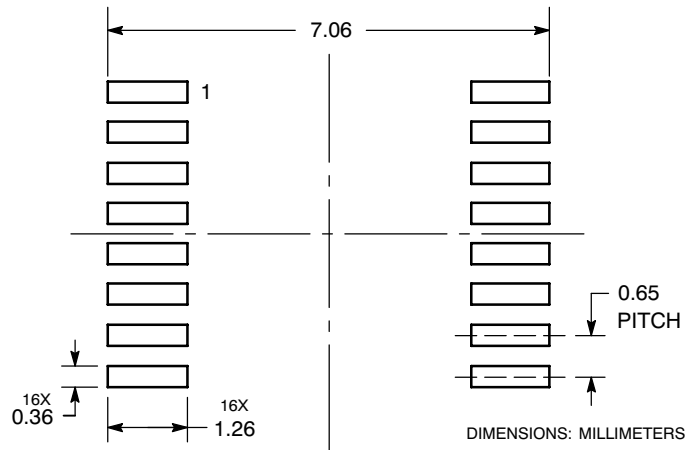


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC	---	0.026 BSC	---
H	0.18	0.28	0.007	0.011
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC	---	0.252 BSC	---
M	0°	8°	0°	8°

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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